

## **Excellent Integrated System Limited**

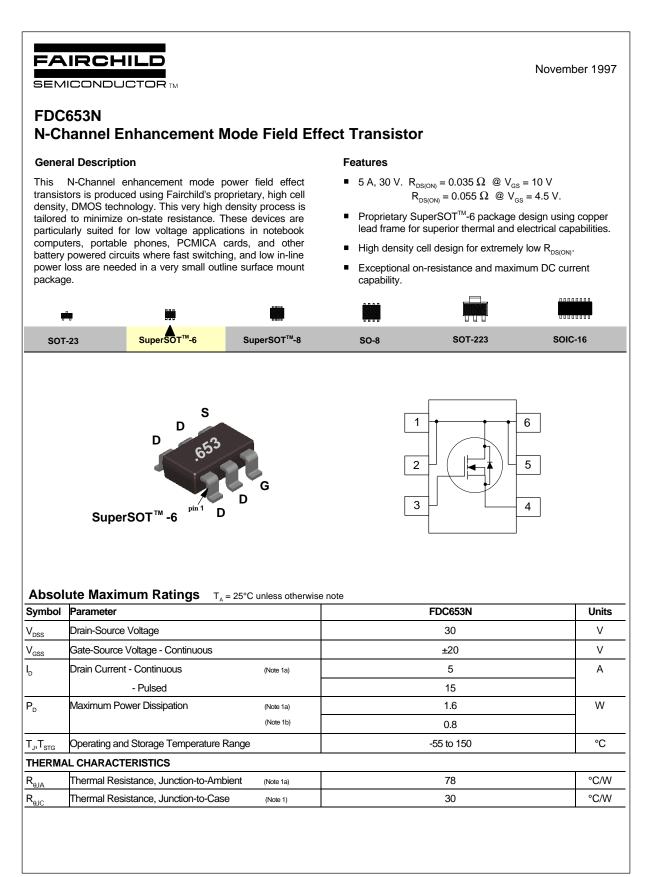
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Fairchild Semiconductor FDC653N

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FDC653N Rev.C



Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS				•		
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$		30			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = 250 µA, Referenced to 25 °C			31		mV /°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$				1	μA
			T, = 55°C			10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$	Ŭ			100	nA
I	Gate - Body Leakage, Reverse	V <sub>GS</sub> = -20 V, V <sub>DS</sub> = 0 V				-100	nA
	CTERISTICS (Note 2)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$		1	1.7	2	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold VoltageTemp.Coefficient	$I_{\rm D}$ = 250 µA, Referenced to	o 25 °C		-4.2		mV /°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_{D} = 5 \text{ A}$			0.027	0.035	Ω
20(01)			T_ = 125°C		0.042	0.056	
		$V_{GS} = 4.5 \text{ V}, I_{D} = 4.2 \text{ A}$	Ŭ		0.046	0.055	
l <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 5 \text{ V}$		8			А
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_{D} = 5 \text{ A}$			6.2		S
DYNAMIC C	HARACTERISTICS				•		
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$			350		pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz			220		pF
C <sub>rss</sub>	Reverse Transfer Capacitance				80		pF
SWITCHING	CHARACTERISTICS (Note 2)						
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ A},$ $V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$			7.5	15	ns
t,	Turn - On Rise Time				12	25	ns
t <sub>D(off)</sub>	Turn - Off Delay Time				13	25	ns
t,	Turn - Off Fall Time				6	15	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = 15 \text{ V}, \ I_{D} = 5 \text{ A},$			12	17	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 10 V$			2.1		nC
Q <sub>gd</sub>	Gate-Drain Charge				2.6		nC
DRAIN-SOL	IRCE DIODE CHARACTERISTICS						-
l <sub>s</sub>	Continuous Source Diode Current					1.3	А
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 1.3 A$ (Not			0.75	1.2	V
			T_ = 125°C		0.6	1	

Notes:

1. R<sub>BM</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BMC</sub> is guaranteed by design while R<sub>BMC</sub> is determined by the user's board design.

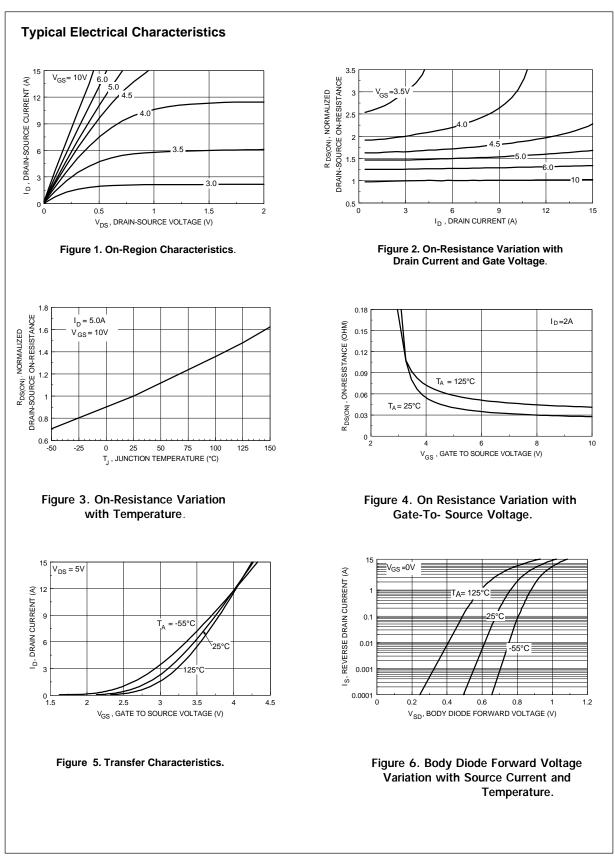
a. 78°C/W when mounted on a minimum on a 1 in² pad of 2oz Cu in FR-4 board.

b. 156°C/W when mounted on a minimum pad of 2oz Cu in FR-4 board.

2. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2.0%.

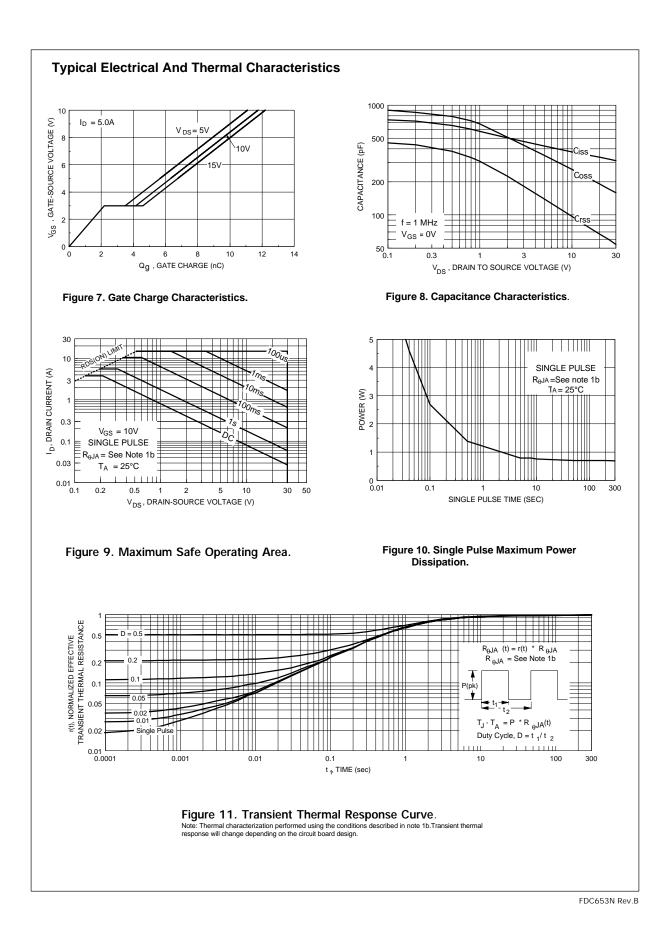
FDC653N Rev.C





FDC653N Rev.B







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